

PbFreeProduct

NCE10TD60BD

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600V, 10A, Trench FS II Fast IGBT

General Description:

Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 600V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low V_{CE(sat)}
- High speed switching
- Positive temperature coefficient in V_{CE(sat)}
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Air Condition
- Inverters
- Motor drives

Package Marking and Ordering Information

Device	Device Package	Device Marking		
NCE10TD60BD	TO-263	NCE10TD60BD		



Schematic diagram

TO-263

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Value	Units	
VCES	Collector-Emitter Voltage	600	V	
V _{GES}	Gate- Emitter Voltage	±30	V	
I	Collector Current	20	A	
lc	Collector Current @T _c = 100 °C	10	A	
ICplus	Pulsed Collector Current, t _p limited by T _{jmax}	30	A	
-	turn off safe operating area, V _{CE} =600V, Tj=150°C	30	А	
lF	Diode Continuous Forward Current @T _c = 100 °C	10	А	
IFM	Diode Maximum Forward Current	30	A	
D	Power Dissipation @ T _C = 25°C	83	W	
PD	Power Dissipation @T _c = 100°C	41.5	W	
TJ,Tstg	Operating Junction and Storage Temperature Range	-55 to +175	°C	
TL	Maximum Temperature for Soldering	260	°C	
t _{sc}	Short circuit withstand time V _{GE} =15 V, V _{CC} \leqslant 400V, Allowed number of short circuits<1000Time between short circuits: \geq 1.0s,T _j \leqslant 150°C	5	us	



Thermal Characteristic

Symbol	Parameter	Value	Units
Rejc	Thermal Resistance, Junction to case for IGBT	1.80	°C/W
Rejc	Thermal Resistance, Junction to case for Diode	2.35	°C/W
Reja	Thermal Resistance, Junction to Ambient	65	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)

Queek c.	Denometer	Test Conditions		Value			
Symbol	Parameter			Min.	Тур.	Max.	Units
Static Chara	cteristics			L			
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V	,I _{CE} =1mA	600			V
ICES	Collector-Emitter Leakage Current	V _{GE} =0V,V _{CE} =600V				4	uA
IGES(F)	Gate to Emitter Forward Leakage	V _{GE} =+30V,V _{CE} =0V				100	nA
I _{GES(R)}	Gate to Source Reverse Leakage	V _{GE} =-30	V,Vce =0V			100	nA
Marken	Collector-Emitter Saturation Voltage	Ic=10A	Tj=25°C		1.7	1.9	V
V _{CE(sat)}	Collector-Emitter Saturation voltage	V_{GE} =15V	Tj=100°C		1.9		V
$V_{\text{GE(th)}}$	Gate Threshold Voltage	Ic=1mA	,Vce=Vge	4.0	5.0	6.0	V
Dynamic Cha	aracteristics						
Cies	Input Capacitance	۱/ oc)			1127		
Coes	Output Capacitance	V _{CE} =25V,V _{GE} =0V, f=1MHz			40		pF
Cres	Reverse Transfer Capacitance				24		
Qg	Total Gate Charge	Vcc=480V, Ic=10A V _{GE} =15V			44		nC
Qge	Gate to Emitter Charge				10		
Q _{gc}	Gate to Collector Charge				19		
I _{C(SC)}	Short circuit collector current Max.1000 short circuits Time between short circuits: \ge 1.0s	V _{GE} =15V,V _{CC} ≪400V, t _{SC} ≪5us,Tj≪150°C			50		А
Switching C	haracteristics						
t _{d(ON)}	Turn-on Delay Time				20		
tr	Rise Time	V _{CC} =400V,Ic=10A V _{GE} =0/15V, R _g =5Ω			15		ns
$t_{\text{d}(\text{OFF})}$	Turn-Off Delay Time				73		
t _f	Fall Time				18		
Eon	Turn-On Switching Loss	Inducti	ve Load		0.21		
E _{off}	Turn-Off Switching Loss				0.11		mJ
Ets	Total Switching Loss				0.32		

Electrical Characteristics of the Diode(Tc= 25°C unless otherwise specified):

Symbol	Parameter	Toot Conditions	Rating			Units
Symbol		Test Conditions	Min.	Тур.	Max.	Units
Vfm	Diode Forward Voltage	IF=10A		1.5	1.7	V
Trr	Reverse Recovery Time			158		ns
IRRM	Diode Peak Reverse Recovery Current	I _F =10A, di/dt=200A/us		5.8		А
Qrr	Reverse Recovery Charge			0.5		uC
Pulse width t _{tp} ≤380μs,δ≤2%						

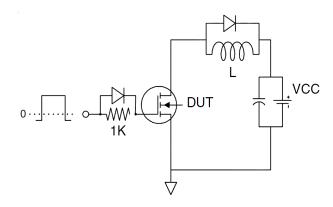




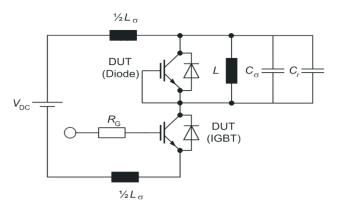
NCE10TD60BD

Test Circuit

1) Gate Charge Test Circuit

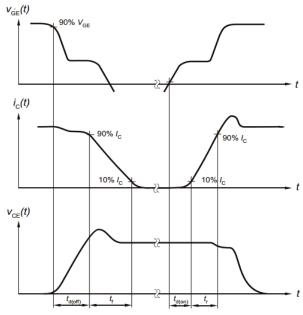


2) Switch Time Test Circuit

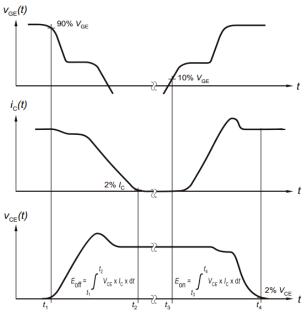


Switching characteristics

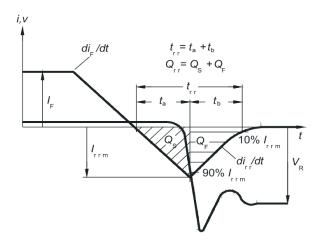
1) Definition of switching times



2) Definition of switching losses

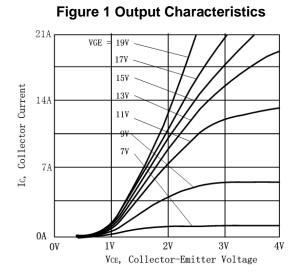


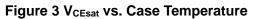
3) Definition of diode switching characteristics





Typical Electrical and Thermal Characteristics





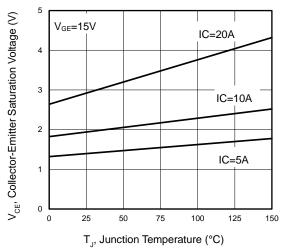
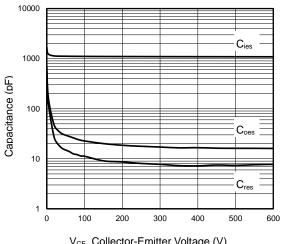


Figure 5 Capacitance Characteristics



V_{CE}, Collector-Emitter Voltage (V)

Figure 2 Transfer Characteristics

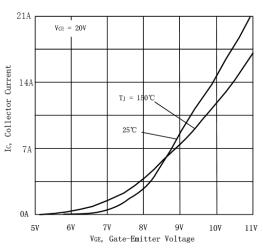


Figure 4 Saturation Voltage vs. VGE

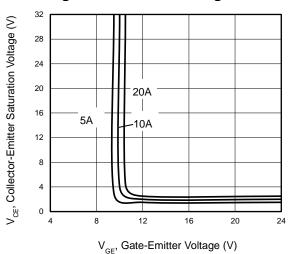
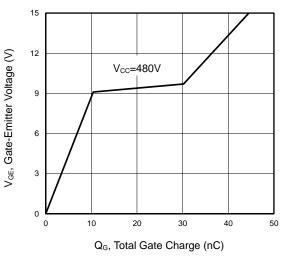
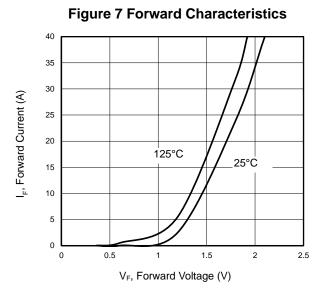


Figure 6 Gate charge waveform





Typical Electrical and Thermal Characteristics





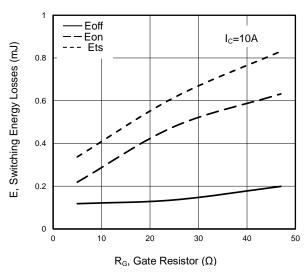
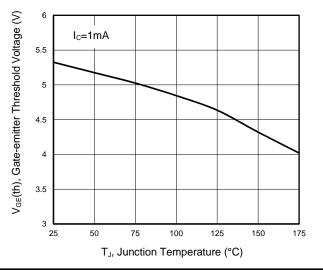


Figure 11 Gate-emitter Threshold Voltage as a Function of Junction Temperature



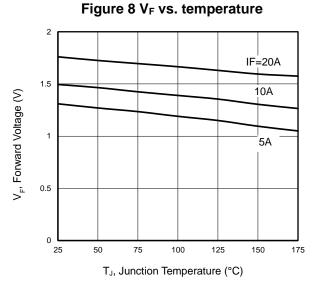


Figure 10 Typical Switching Times as a Function of Junction Temperature

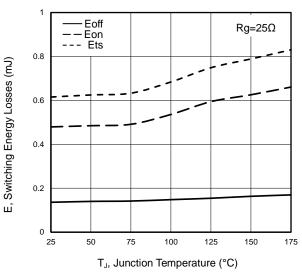
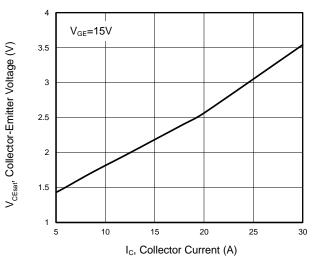


Figure 12 Typical Collector-emitter Saturation Voltage as a function of Collector Current





Typical Electrical and Thermal Characteristics

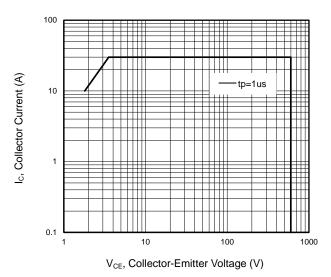
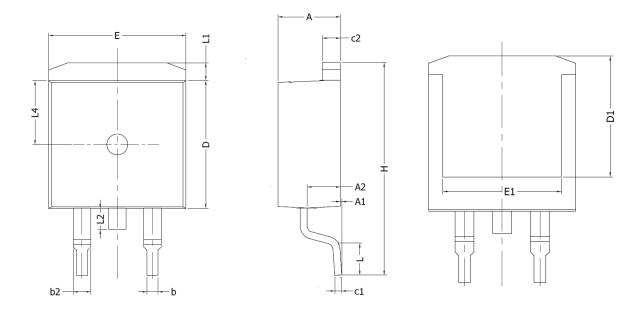


Figure 13 Forward Bias Safe Operating Area



TO-263-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
oymbol	Min.	Max.	Min.	Max.	
A	4.40	4.60	0.17	0.18	
A1	0.00	0.25	0.00	0.01	
A2	2.20	2.60	0.09	0.10	
b	0.76	0.89	0.03	0.04	
b2	1.23	1.37	0.05	0.05	
С	0.47	0.60	0.02	0.02	
c1	0.46	0.56	0.02	0.02	
c2	1.25	1.35	0.05	0.05	
D	0.91	0.93	0.04	0.04	
D1	8.00	-	0.31	-	
E	9.80	10.00	0.39	0.39	
E1	7.80	-	0.31	-	
е	2.5	2.54BSC		BSC	
Н	14.90	15.70	0.59	0.62	
L	2.00	2.60	0.08	0.10	
L1	1.17	1.40	0.05	0.06	
L2	-	1.75	-	0.07	
L4	4.6	0REF	0.18REF		



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